


SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

STK760-211C-E — Thick-Film Hybrid IC Single-phase rectification Active Converter Hybrid IC

Overview

This IC is average current control type Active Converter Hybrid IC for power factor improvement of single-phase AC power supply, that containing power devices of step-up active converter, control IC over-current and over-voltage protection circuits.

Applications

- Single-phase rectification active filter for power rectification for air conditioners and general-purpose inverters.

Features

- Power switching device for active converter is adopting IGBT.
- Soft start functions and the over current, the over voltage, and the low-voltage are including as protection circuit
- Capable of controlling ON/OFF by logic level input signal.
- Output voltage changeability functions by control signal.

■ Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment. The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for new introduction or other application different from current conditions on the usage of automotive device, communication device, office equipment, industrial equipment etc. , please consult with us about usage condition (temperature, operation time etc.) prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.

■ Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.

SANYO Semiconductor Co., Ltd.
<http://www.sanyosemi.com/en/network/>

Specifications

Absolute Maximum Ratings at $T_a = 25^{\circ}\text{C}$

Parameter		Symbol	Conditions	Ratings	unit
IGBT (TR1+TR2)	Collector-emitter voltage	VCE		600	V
	Repetitive peak collector current	ICP	*1	185	A
	Collector current	IC		72	A
	Power dissipation	PC1		125	W
FRD1 (D1)	Diode reverse voltage	VRM		600	V
	Repetitive peak forward current	IF1P	*1	106	A
	Diode forward current	IF1		36	A
	Power dissipation	PD1		73	W
FRD2 (D2)	Repetitive peak forward current	IF2P	*1	15	A
	Diode forward current	IF2		7	A
	Power dissipation	PD2		13	W
Supply voltage (V _{CC} -GND)		V _{CC}		20	V
Signal pin input voltage		Pin 4	VIS	-10 to 0.3	V
		Pin 5	VCOMP	-0.3 to 6.5	
		Pin 8	VFB		
		Pin 9	VOVP		
		Pin 2	VONF	-0.3 to V _{CC}	
		Pin 6	Vctl		
Maximum input AC voltage		VAC	Single-phase Full-rectified	264	V
Maximum output voltage		V _O	Under the Application condition (VAC=200V)	450	V
Maximum output power		W _o		4	kW
Input AC current (normal condition)		I _{IJN}		20	Arms
Junction temperature		T _J		150	°C
Operating case temperature		T _c	HIC case temperature *2	-20 to +100	°C
Storage temperature		T _{stg}		-40 to +125	°C
Tightening torque			A screw part *3	1.0	N•m
Withstand voltage		VINS	50Hz sine wave AC 1minute *4	2000	VRMS

[Note]

*1: Duty ratio $D = 0.1$, $t_p = 1\text{ms}$

*2: Measure point is between 5mm to center of back.

*3: Torque should be set within 0.79 to 1.0N•m. Flatness of the heat-sink should be lower than 0.15mm.

*4: The test condition: AC2500V, 1 second.

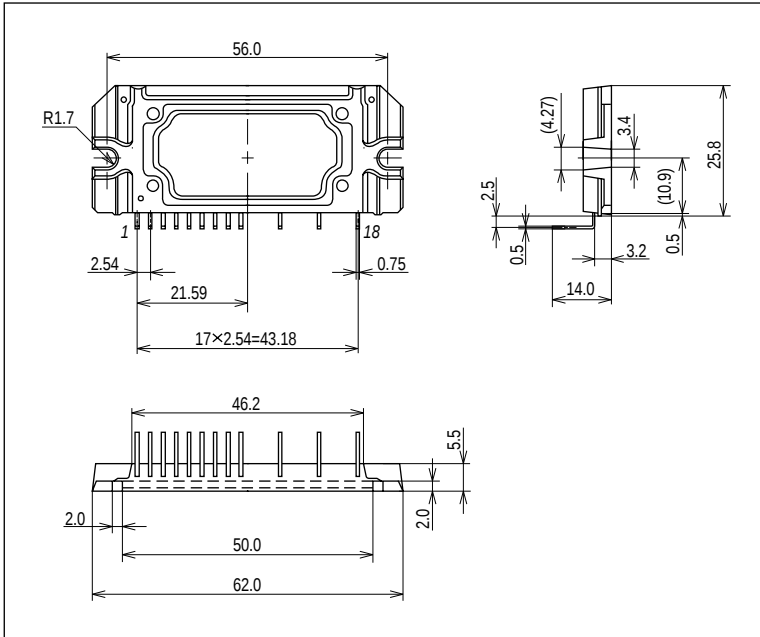
STK760-211C-E

Electrical Characteristics at $T_c = 25^\circ\text{C}$, $V_{CC} = 15.0\text{V}$: Unless otherwise noted

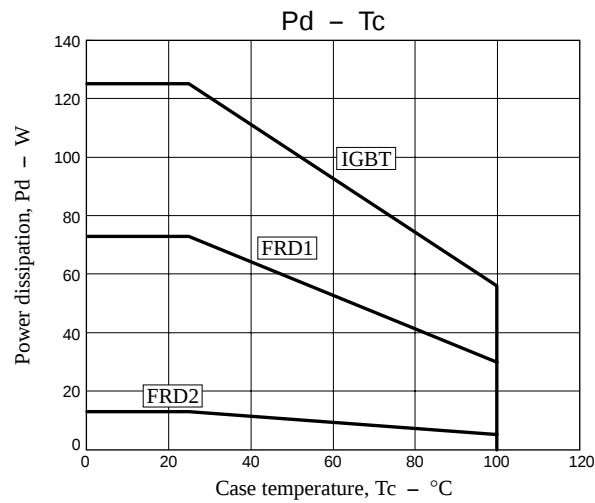
Parameter	Symbol	Conditions	Test circuit	Ratings			unit
				min	typ	max	
Power output part							
Collector-emitter leak current (IGBT)	I _{CES}	V _{CE} = 600V	Fig.1			200	μA
Collector-emitter saturation voltage (IGBT)	V _{CE(sat)}	I _C = 30A	Fig.2		1.4	2.0	V
Diode reverse current (FRD1)	I _R	V _R = 600V	Fig.1			200	μA
Diode forward voltage (FRD1)	V _{F1}	I _F = 30A	Fig.3		2.0	2.6	V
Diode forward voltage (FRD2)	V _{F2}	I _F = 5A	Fig.3		2.5	3.5	V
Junction to case thermal resistance	θj-c1	IGBT (TR1+TR2)			1.0		°C/W
	θj-c2	FRD1 (D1)			1.7		°C/W
	θj-c3	FRD2 (D2)			9.0		°C/W
Control IC part							
Control IC input current	I _{CC(ON)}	V _{CC} = 15V, VONF = 5V	Fig.4		14	20	mA
	I _{CC(OFF)}	V _{CC} = 15V, VONF = 0V			2.5	5	
Oscillation frequency	f _{OSC}	V _{CC} = 15V, VONF = 5V			19.5	22.0	24.5
Open loop protection threshold voltage	VOLP		Fig.5	0.8	0.95	1.1	V
Error-amp reference voltage	Vref			4.88	5.0	5.12	V
Peak current protection threshold voltage	VIS(PK)			-0.58	-0.5	-0.42	V
Over voltage protection threshold voltage	VOVP(ON)		Fig.6	5.095	5.3	5.51	V
ON/OFF threshold voltage	VTHON	V _{CC} = 15V	Fig.7	3.0			V
	VTHOFF					0.5	V
Start-up V _{CC} voltage	V _{CC(ON)}	VONF = 5V	Fig.8	12.4	13.25	14.1	V
Shut-down V _{CC} voltage	V _{CC(OFF)}			9.4	10.0	10.7	V
Application circuit : VAC = 200V, V _O = 380V (V _{ctl} = 1.507V)							
Output voltage	V _O	W _o = 2kW	Fig.9	366	380	394	V
Power Factor	cosφ	W _o = 400W		0.98	0.99		
		W _o = 2kW		0.99	0.995	1.0	

Package Dimensions

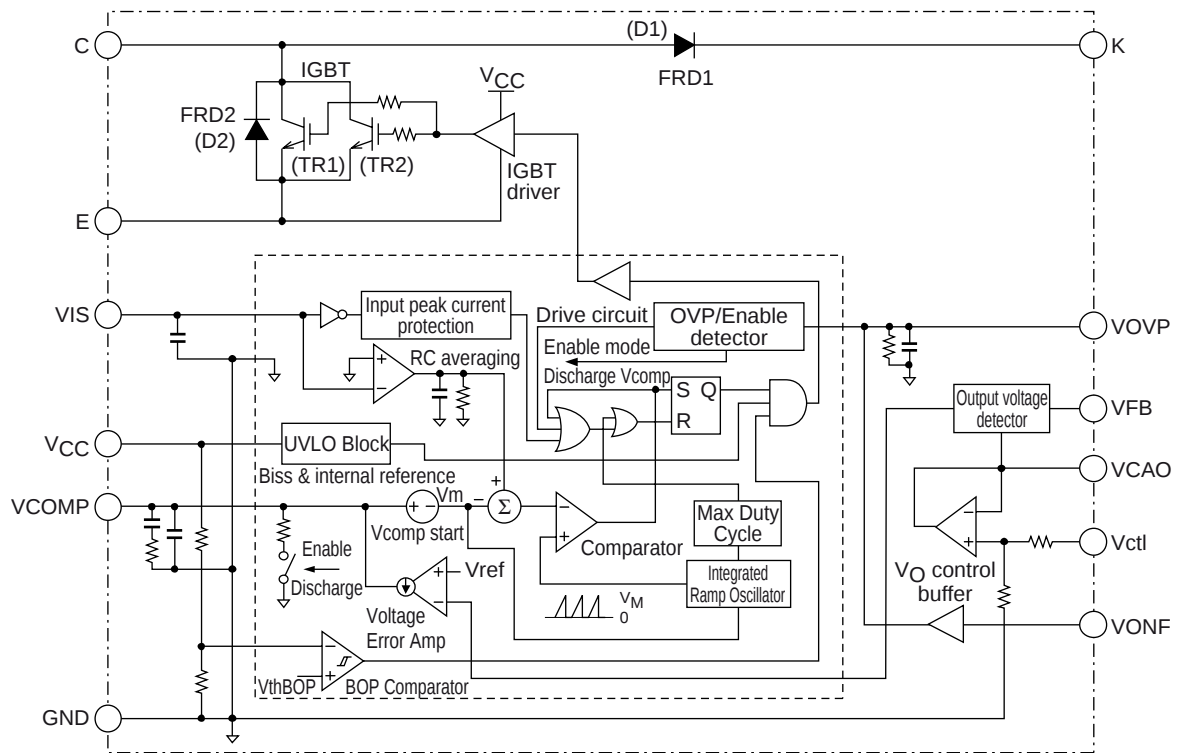
unit:mm (typ)



IGBT (TR1+TR2), FRD1 (D1) & FRD2 (D2) vs. Temperature Derating ($T_a = 25^\circ\text{C}$)



Block Diagram



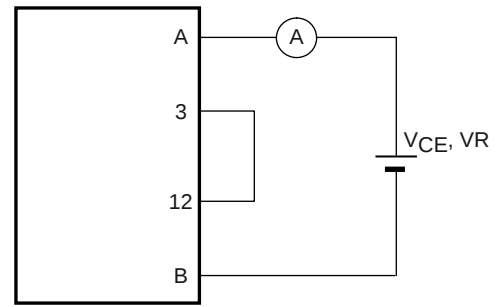
Explanation of Terminal

Terminal No.	Symbol	Explanation
1	V _{CC}	Control IC power supply input
2	VONF	ON/OFF control terminal
3	GND	Signal GND
4	VIS	Current detection terminal
5	VCOMP	Phase compensation terminal (Voltage error amplifier out)
6	Vctl	Output voltage control signal input
7	VCAO	Output voltage control amplifier output
8	VFB	Output voltage feed back terminal
9	VOVP	Over voltage protection terminal
10, 11	-	An empty terminal
12	E	IGBT (TR1+TR2) Emitter
13, 14	-	An empty terminal
15	C	IGBT (TR1+TR2) Collector
16, 17	-	An empty terminal
18	K	FRD1 (D1) Cathode

Test Circuit -1

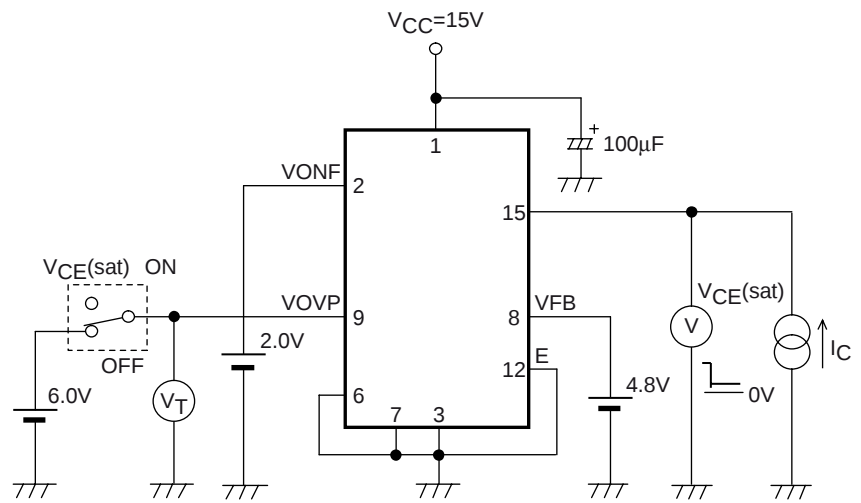
(1) I_{CES} , I_R

	IGBT	FRD1
A	15	18
B	12	15



〈Fig.1〉

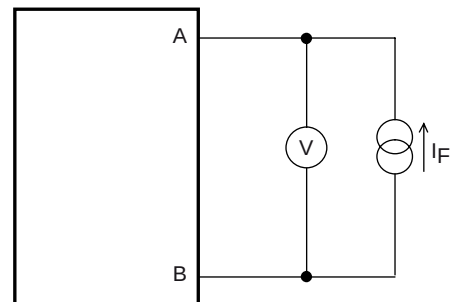
(2) $V_{CE(sat)}$ (Test by Pulse)



〈Fig.2〉

(3) V_{F1} , V_{F2} (Test by Pulse)

	FRD1	FRD2
A	15	12
B	18	15

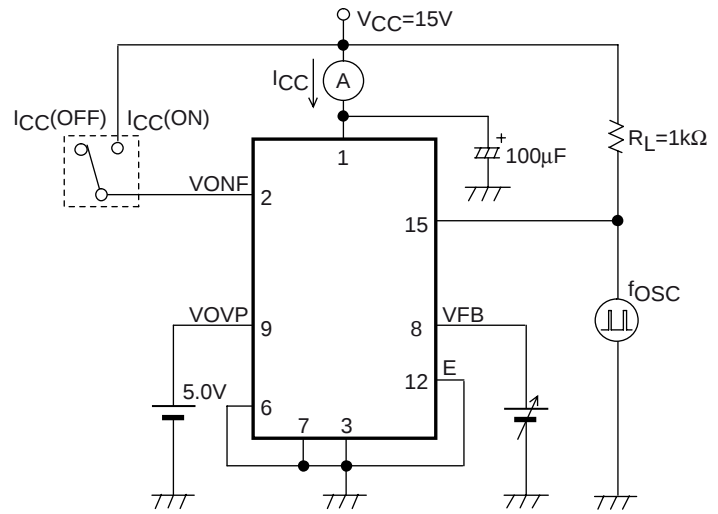


〈Fig.3〉

Test Circuit -2

(4) $I_{CC}(ON)/I_{CC}(OFF)$, $VOLP$, f_{OSC}

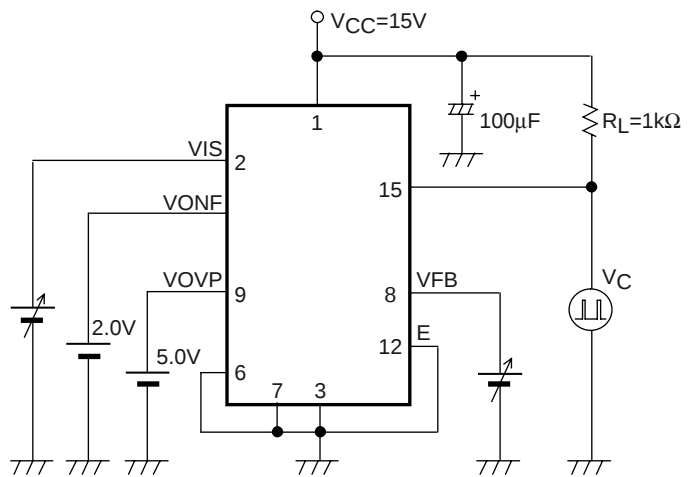
I_{CC}, f_{OSC}	$VOLP$
$VFB = 1.1V$	$VONF = 5.0V$



(Fig.4)

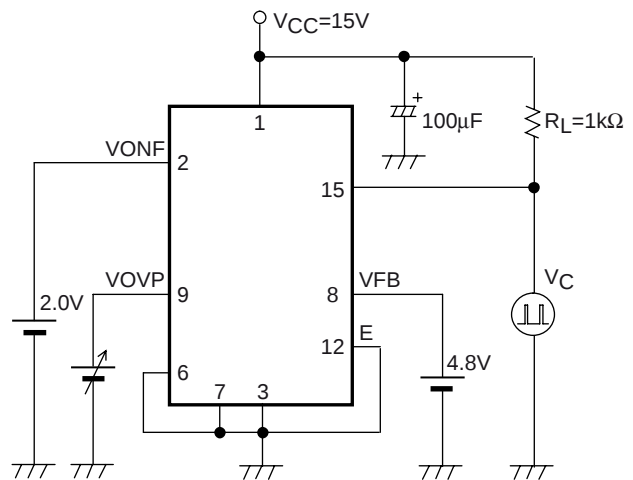
(5) V_{ref} , $VIS(PK)$

V_{ref}	$VIS(PK)$
$VIS = -0.6V$	$VFB = 4.8V$



(Fig.5)

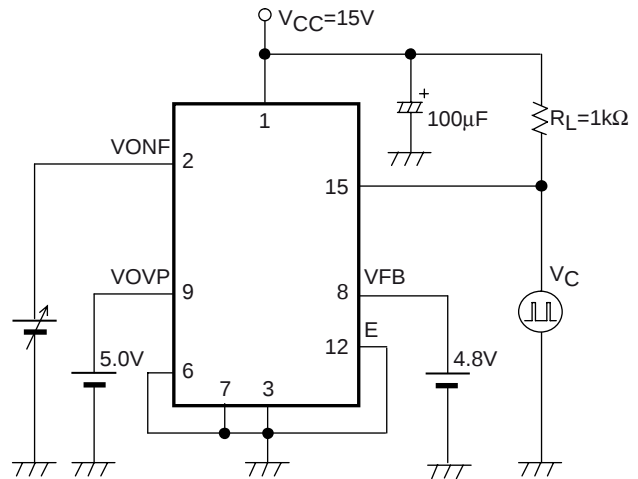
(6) $VOVP(ON)$



(Fig.6)

Test Circuit -3

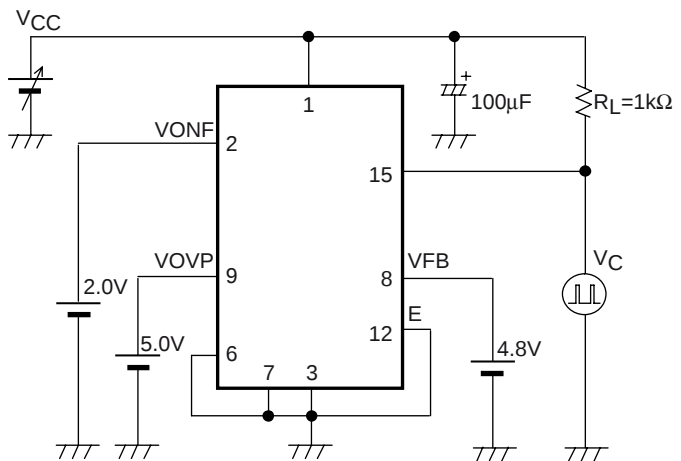
(7) V_{THON}, V_{THOFF}



(Fig.7)

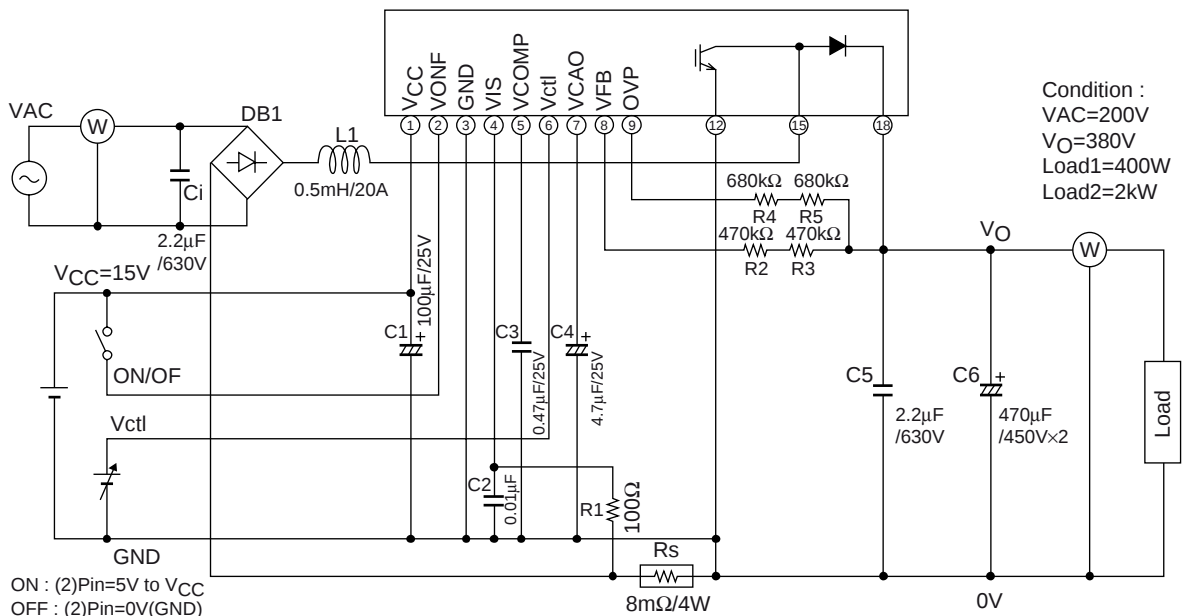
(8) V_{CC(ON)}, V_{CC(OFF)}

V _{CC(ON)}	V _{CC(OFF)}
V _{c-ON}	V _{c-OFF}



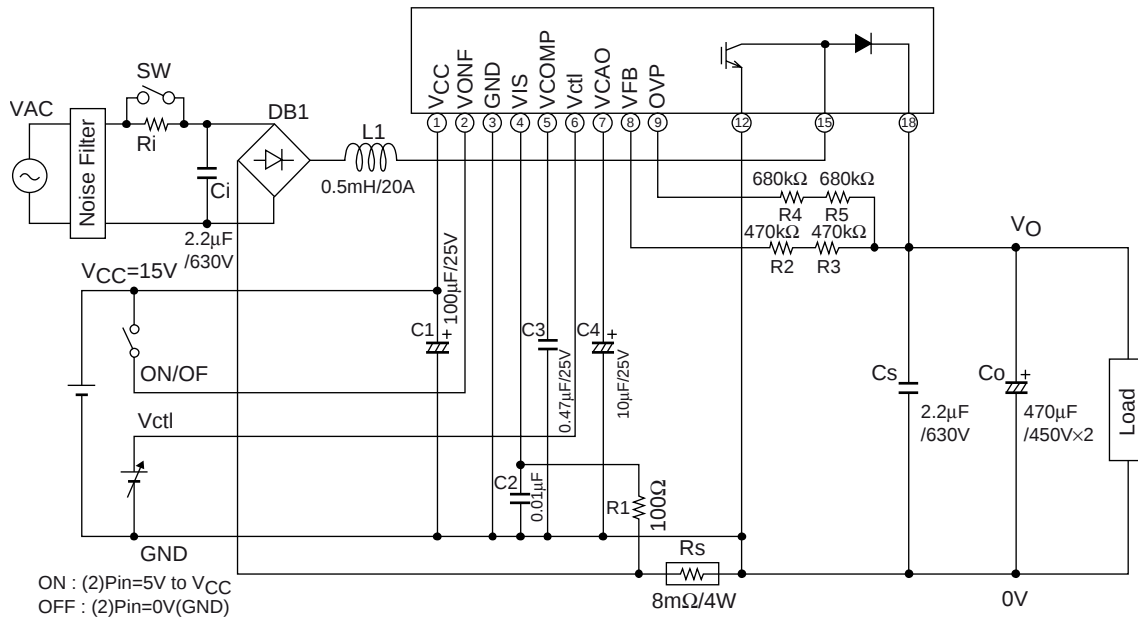
(Fig.8)

(9) Power Factor (COSφ)



(Fig.9)

Application Circuit

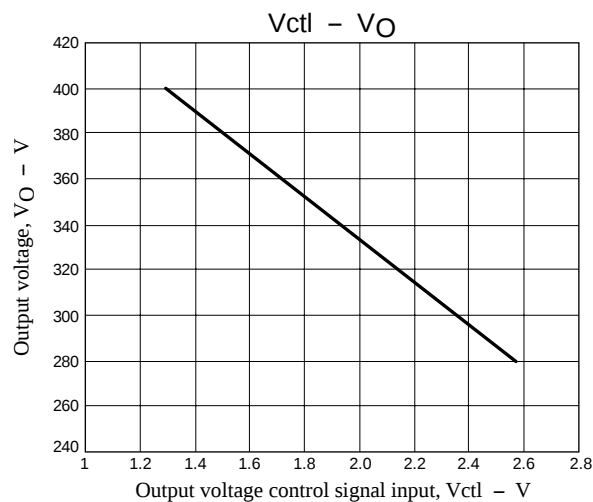


Recommended Condition

Parameter	Symbol	Conditions	Ratings	unit
AC Voltage	VAC	50/60Hz	170 to 264	Vrms
Output voltage	V _O		$VAC \times \sqrt{2} + (10 \text{ to } 15) \leq 450$	V
Over-voltage detection voltage	VOV		$V_{OUT} + (10 \text{ to } 20)$	V
Control IC supply voltage	V _{CC}	V _{CC} -GND	14.5 to 17.0	V
Inductor	L1		0.5	mH
Input film capacitor	Ci		$2.2 \leq C_i$	μF
Output film capacitor	Cs		$2.2 \leq C_s$	μF
Output electrolytic capacitor	Co		$940 \leq C_o$	μF

Output Voltage Control

Output voltage control signal V_{ctl} sets referring to the V_{ctl}-V_O characteristic of the figure below.



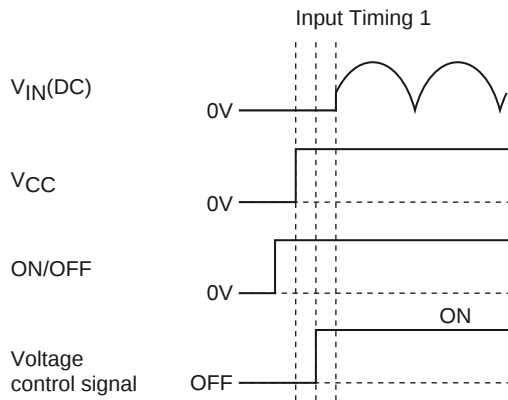
Timing Chart

Even if power supply and signal at any timing are input, this IC is not destroyed.

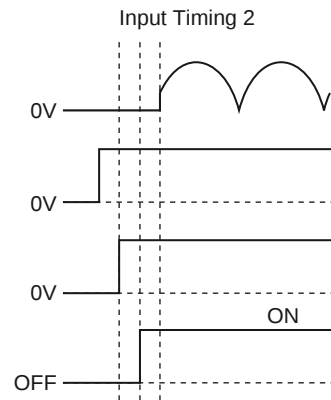
However, soft start circuit doesn't operate when $V_{IN}(DC)$ is input at the timing of Figure 11 and 12.

Therefore, overcurrent protection circuit will operate, and audio frequency noise from coil may generate.

Please turn on ON/OFF or V_{CC} after $V_{IN}(DC)$ to avoid this.



〈Fig.11〉



〈Fig.12〉

- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- Regarding monolithic semiconductors, if you should intend to use this IC continuously under high temperature, high current, high voltage, or drastic temperature change, even if it is used within the range of absolute maximum ratings or operating conditions, there is a possibility of decrease reliability. Please contact us for a confirmation.
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co.,Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of October, 2012. Specifications and information herein are subject to change without notice.